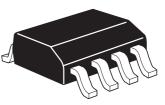


ZLNB1001 DBS tone and polarity multiplex controller

Description

The ZLNB1001 multiplex controller is one of a wide range of satellite receiver LNB and IF distribution support circuits available from Zetex. It supports a single IF path providing logic outputs to select one of four IF switch input channels, which typically using PIN diodes. It is intended for use in multi-switch applications for selection and distribution of universal LNB IF output signals, replacing many discrete components including the voltage regulator to save both manufacturing cost and PCB size whilst improving reliability.



The highly accurate control input of the ZLNB1001 has both voltage and tone control for the four required states. The voltage threshold is nominally 14.5 V and to meet the demanding requirements of some broadcasters it has a switching range of 14.0 V to 15 V. The threshold is temperature compensated to minimize drift. This features a low and stable input current that enables transient protection to be achieved with the addition of only a single resistor.

The outputs are configured to deliver a positive regulated voltage drive of 7 V when a desired channel is selected, and 0V when de-selected.

Features

- Precision voltage and tone detectors
- Temperature compensated
- Low cost solution
- Integrated tone filter
- Powered from STB: no additional power requirement
- Direct drive to PIN diodes
- SO8 SMD package

Applications

- Switch boxes for satellite IF distribution
- LNB receivers

Pin out - top view

VIN 🗀	1 8	₩ VOUT4
VPOL	2 7	□ VOUT3
FIN 🗀	3 6	□ VOUT2
GND 🗀	4 5	₩ VOUT1

Absolute maximum ratings

Input voltage 25V

Output current 50mA

Operating temperature -40 to 85°C Storage temperature -50 to 150°C

Electrical characteristics

Test conditions (unless otherwise stated): Vin = 10V to 21V via series resistor as test circuit, $T_{amb} = 25^{\circ}C$

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
I _S	Supply current	I _{OUT} = 0	1.5	3.2	5.5	mA
I _{POL}	Input current at V _{POL}	V _{POL} = 15V V _{in} = 15V	130	220	350	μА
V _{TVPOL} *	Threshold voltage	T_{amb} = -40 to 80°C V_{in} = 15V	14	14.5	15	V
V _{TFIN}	Tone threshold	f = 22kHz [†]	100	170	350	mV p-p
V _{OUTH}	Output voltage "high"	For selected output, I _{OUT} = 20 mA (source)	6.5	7	7.5	V
		For selected output, I _{OUT} = 0	7.5	8	8.5	V
V _{OUTL}	Output voltage "low"	For unselected output, I _{OUT} = -1 mA (sink)		0.15	0.5	٧
T _{SW}	Switching speed				10	ms

NOTES:

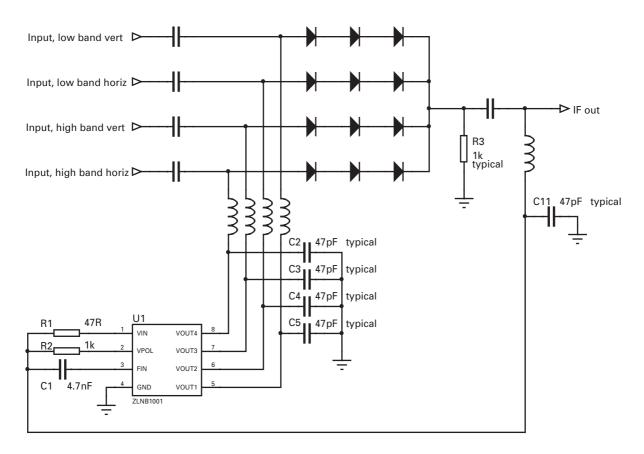
Truth table

Tone	V _{POL}	Output 1	Output 2	Output 3	Output 4	Satellite signal
Off	< V _{TPOL}	High	Low	Low	Low	Low band Vert
Off	> V _{TPOL}	Low	High	Low	Low	Low band Horiz
On	< V _{TPOL}	Low	Low	High	Low	High band Vert
On	> V _{TPOL}	Low	Low	Low	High	High band Horiz

^{*} Threshold voltage is adjustable using external resistor.

[†] Waveform of 22 kHz tone is shown in test circuit diagram.

Typical application circuit using pin diodes

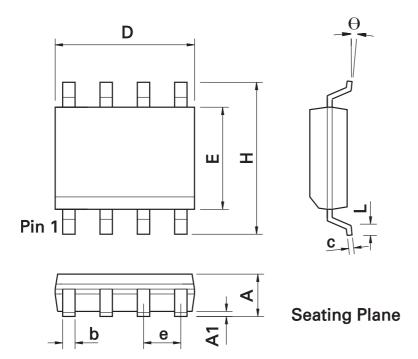


Application information

The schematic diagram above shows the typical application driving RF signal PIN diodes. Values of suitable external components are shown. R1 R2 and C1 are required to achieve specified operation. Values of other components are typical of the application. When one signal path is selected according to the Truth Table, the selected signal diodes carry a forward current set by R3. The other signal diodes are biased off, R3 providing a degree of reverse bias.

In order to limit the peak current in the device, it is recommended that the output decoupling capacitor value, including C2, C3, C4 and C5, should not be excessive. Normally this total is expected to be less than a few hundred pF in the intended application.

Package details - SO8



Package dimensions

Dimensions in inches are control dimensions, dimensions in millimeters are approximate.

DIM	Millin	neters	Inc	hes	DIM	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
Α	1.35	1.75	0.053	0.069	е	1.27 BSC		0.050 BSC	
A1	0.10	0.25	0.004	0.010	b	0.33	0.51	0.013	0.020
D	4.80	5.00	0.189	0.197	С	0.19	0.25	0.008	0.010
Н	5.80	6.20	0.228	0.244	θ	0°	8°	0°	8°
Е	3.80	4.00	0.150	0.157	h	0.25	0.50	0.010	0.020
L	0.40	1.27	0.016	0.050	-	-	-	-	-

Asia Pacific Europe Americas **Corporate Headquarters** Zetex Semiconductors plc Zetex GmbH Zetex Inc Zetex (Asia Ltd) Zetex Technology Park, Chadderton Oldham, OL9 9LL Streitfeldstraße 19 700 Veterans Memorial Highway 3701-04 Metroplaza Tower 1 D-81673 München Hauppauge, NY 11788 Hing Fong Road, Kwai Fong Germany Hong Kong United Kingdom Telephone: (852) 26100 611 Telephone (44) 161 622 4444 Telefon: (49) 89 45 49 49 0 Telephone: (1) 631 360 2222 Fax: (49) 89 45 49 49 49 Fax: (852) 24250 494 Fax: (1) 631 360 8222 Fax: (44) 161 622 4446 hq@zetex.com europe.sales@zetex.com usa.sales@zetex.com asia.sales@zetex.com

These offices are supported by agents and distributors in major countries world-wide.

This publication is issued to provide outline information only which (unless agreed by the company in writing) may not be used, applied or reproduced for any purpose or form part of any order or contact or be regarded as a representation relating to the products or services concerned. The company reserves the right to alter without notice the specification, design, price or conditions of supply of any product or service.